

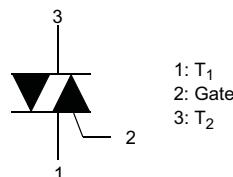
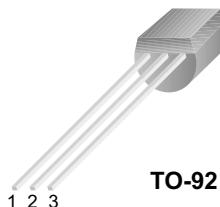


FKN08PN60

TRIAC (Silicon Bidirectional Thyristor)

Application Explanation

- Switching mode power supply, light dimmer, electric flasher unit, hair drier
- TV sets, stereo, refrigerator, washing machine
- Electric blanket, solenoid driver, small motor control
- Photo copier, electric tool



Absolute Maximum Ratings

T_a = 25°C unless otherwise noted

Symbol	Parameter	Value		Rating	Units
V _{DRM} V _{RRM}	Peak Repetitive Off-State Voltage	Sine Wave 50 to 60Hz, Gate Open		600	V
I _T (RMS)	RMS On-State Current	Commercial frequency, sine full wave 360° conduction, T _c = 70°C		0.8	A
I _{TSM}	Surge On-State Current	Sinewave 1 full cycle, peak value, non-repetitive	50Hz	8	A
			60Hz	9	A
I ² t	I ² t for Fusing	Value corresponding to 1 cycle of halfwave, surge on-state current, t _p =8.4ms		0.33	A ² s
P _{GM}	Peak Gate Power Dissipation			5	W
P _G (AV)	Average Gate Power Dissipation			0.1	W
V _{GM}	Peak Gate Voltage			5	V
I _{GM}	Peak Gate Current			1	A
T _J	Junction Temperature			- 40 ~ 125	°C
T _{STG}	Storage Temperature			- 40 ~ 125	°C

Thermal Characteristics

Symbol	Parameter	Value	Units
R _{θJC}	Thermal Resistance, Junction to Case (note1)	40	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient (note2)	160	°C/W

Note1: Infinite cooling condition.

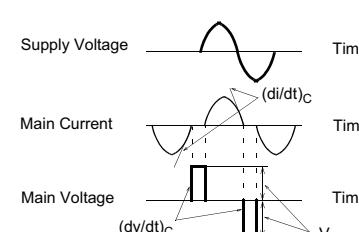
Note2: JESD51-10 (Test Board: FR4 3.0**4.5**0.062", Minimum land pad)

Electrical Characteristics

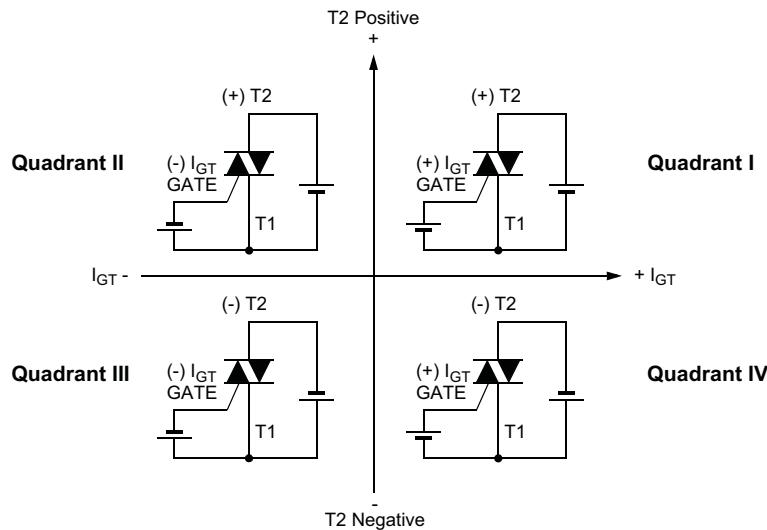
$T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition		Min.	Typ.	Max.	Units	
I_{DRM} I_{RRM}	Repetitive Peak Off-State Current	V_{DRM}/V_{RRM} applied		-	-	100	μA	
V_{TM}	On-State Voltage	$T_C=25^\circ\text{C}, I_{TM}=1.12\text{A}$ Instantaneous measurement		-	-	1.8	V	
V_{GT}	Gate Trigger Voltage	I	$V_D=12\text{V}, R_L=100\Omega$	T2(+), Gate (+)	-	2.0	V	
		II		T2(+), Gate (-)	-	2.0	V	
		III		T2(-), Gate (-)	-	2.0	V	
I_{GT}	Gate Trigger Current	I	$V_D=12\text{V}, R_L=100\Omega$	T2(+), Gate (+)	-	5	mA	
		II		T2(+), Gate (-)	-	5	mA	
		III		T2(-), Gate (-)	-	5	mA	
V_{GD}	Gate Non-Trigger Voltage	$T_j=125^\circ\text{C}, V_D=1/2V_{DRM}$		0.2	-	-	V	
I_H	Holding Current (I, II, III)	$V_D = 12\text{V}, I_{TM} = 200\text{mA}$		-	-	15	mA	
I_L	Latching Current	I, III	$V_D = 12\text{V}, I_G = 10\text{mA}$	-	-	15	mA	
		II		-	-	20	mA	
$dv/dt(s)$	Critical Rate of Rise of Off-State Voltage	$V_{DRM} = 63\%$ Rated, $T_j = 125^\circ\text{C}$, Exponential Rise		20	-	-	V/ μs	
$dv/dt(c)$	Critical-Rate of Rise of Off-State Commutating Voltage ($di/dt=-0.7\text{A}/\mu\text{s}$)			3.0	-	-	V/ μs	

Commutation dv/dt test

V_{DRM} (V)	Test Condition	Commutating voltage and current waveforms (inductive load)
FKN08PN60	1. Junction Temperature $T_j=125^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_C$ 3. Peak off-state voltage $V_D = 300\text{V}$	 <p>The diagram illustrates the waveforms for commutation. It shows three plots: Supply Voltage, Main Current, and Main Voltage. The Supply Voltage is a sinusoidal wave. The Main Current starts at a high value and decays towards zero. The Main Voltage is a rectangular pulse that turns on at the start of the current decay and turns off at the end. Arrows indicate the rate of change of current, labeled $(di/dt)_C$, and the peak off-state voltage, labeled V_D.</p>

Quadrant Definitions for a Triac



Package Marking and Ordering Information

Device Marking	Device	Package	Packing	Tape Width	Quantity
K08PN60	FKN08PN60	TO-92	Bulk	--	--

Typical Performance Characteristics

Figure 1. On-State Characteristics

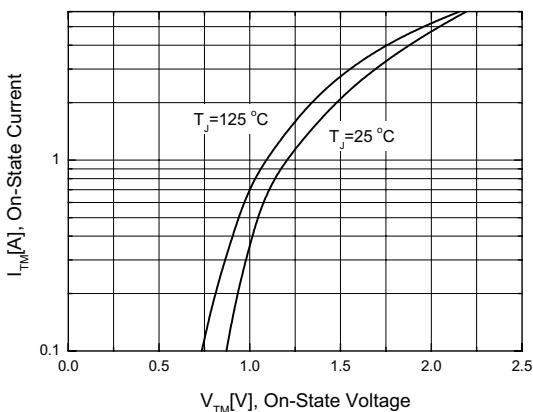


Figure 2. Power Dissipation

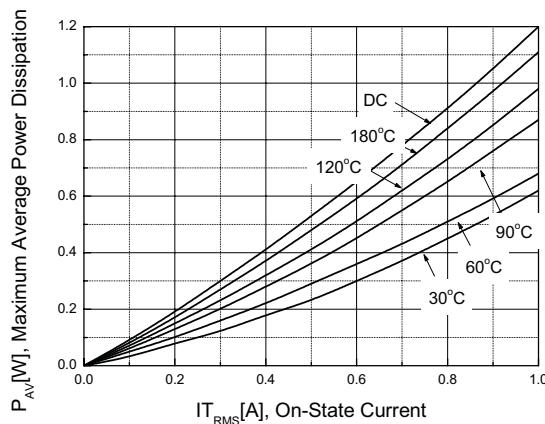


Figure 3. RMS Current Rating

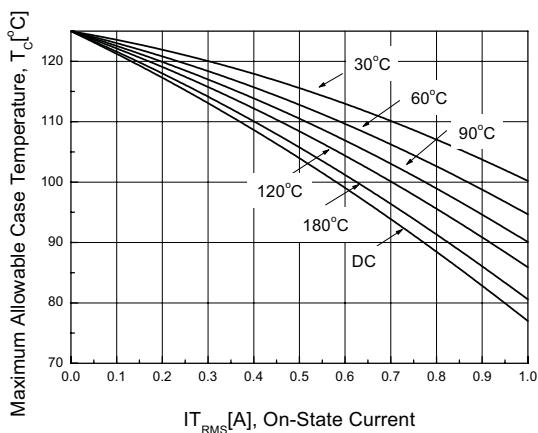


Figure 5. Typical Gate Voltage vs Junction Temperarure

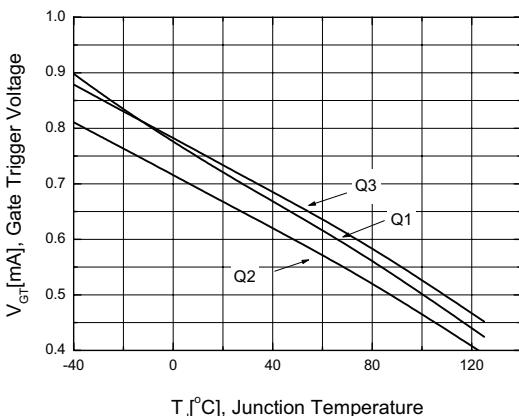


Figure 4. Typical Gate Trigger Current vs Junction Temperature

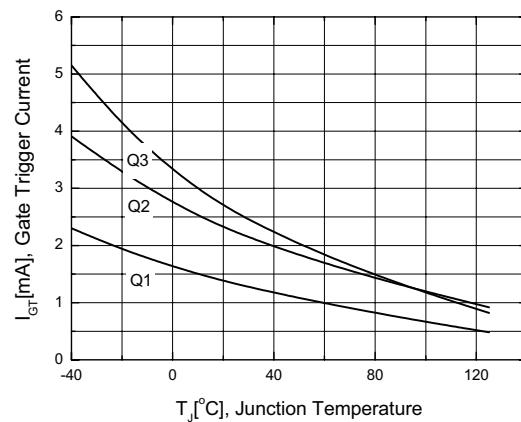
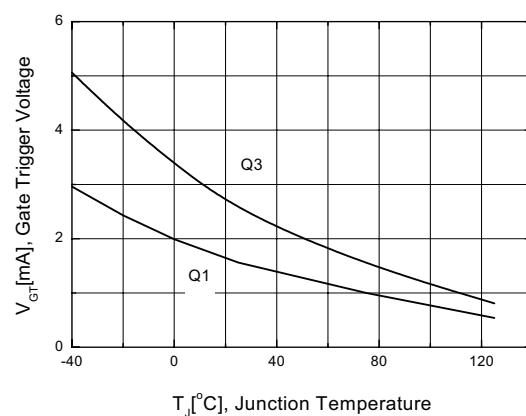


Figure 6. Typical Latching Current vs Junction Temperature



Typical Performance Characteristics (Continued)

Figure7. Typical Holding Current vs Junction Temperature

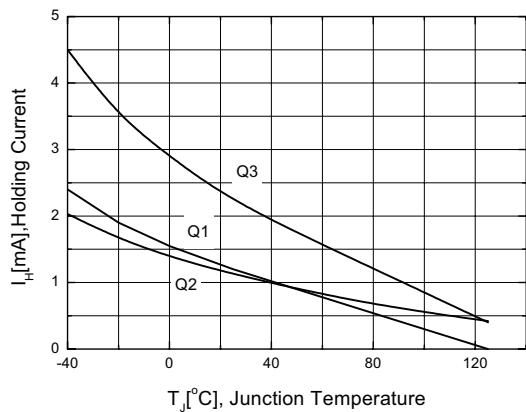
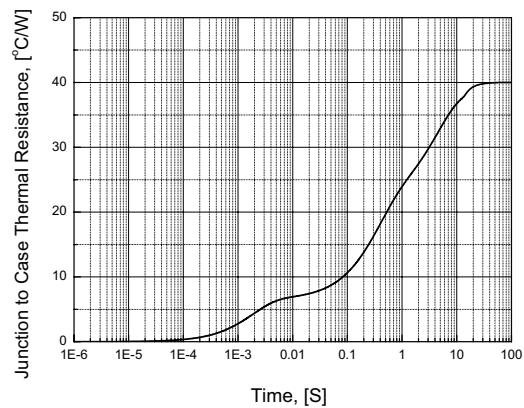
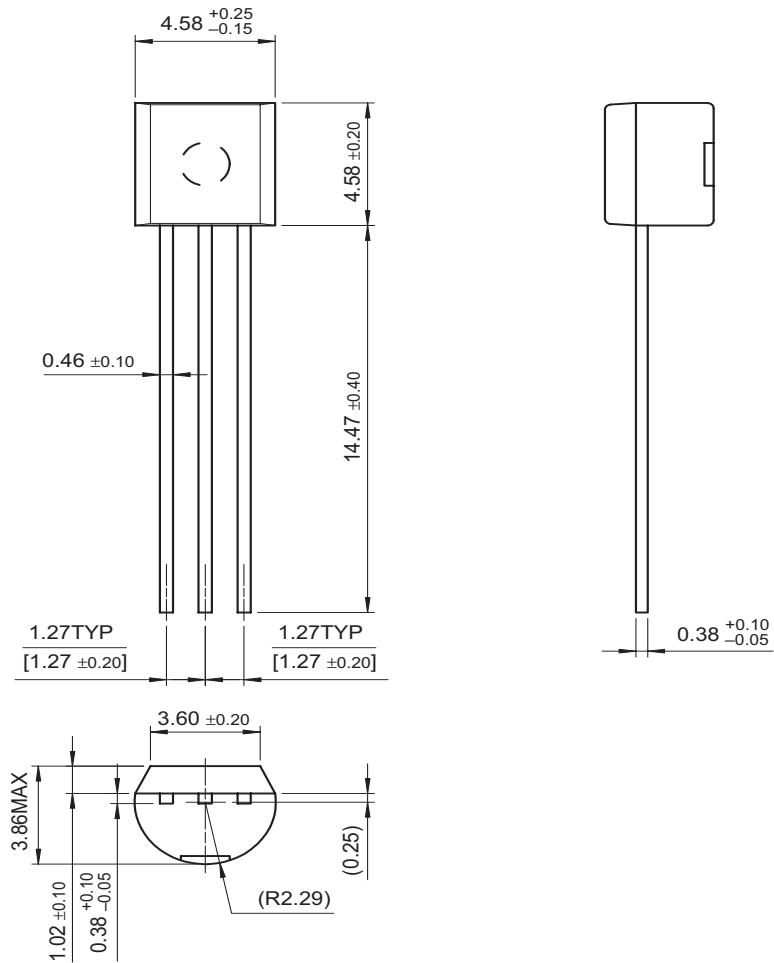


Figure8. Junction to Case Thermal Resistance



Package Dimension

TO-92



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EnSigna™	LittleFET™	PowerTrench®	TCM™	
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FAST®	MicroFET™	QS™	TinyBuck™	
FASTr™	MicroPak™	QT Optoelectronics™	TinyPWM™	
FPS™	MICROWIRE™	Quiet Series™	TinyPower™	
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